



v04.0210

SMT GaAs HBT MMIC x8 ACTIVE FREQUENCY MULTIPLIER, 9.9 - 11.2 GHz OUTPUT

Typical Applications

Active Multiplier for X Band Applications:

- Fiber Optic
- Point-to-Point Radios
- Military Radar

Functional Diagram

N/C Vcc \geq Z \geq 22 24 21 20 19 23 N/C 18 N/C 1 17 N/C N/C 2 16 RFOUT RFIN 3 Χ8 GND 4 15 GND N/C N/C 5 14 N/C N/C 6 13 7 8 9 10 11 12 PACKAGE N/C N/C V/C N/C N/C N/C BASE GND TOP VIEW

Features

Output Power: +6 dBm Sub-Harmonic Suppression: >25 dBc SSB Phase Noise: -136 dBc/Hz Single Supply: +5V@ 68 mA 24 Lead 4x4 mm SMT Package: 16 mm²

General Description

The HMC444LP4 & HMC444LP4E are active miniature x8 frequency multipliers utilizing InGaP GaAs HBT technology in 4x4 mm leadless surface mount packages. Power output is +6 dBm typical from a 5V supply voltage and varies little vs. input power, temperature and supply voltage. Suppression of undesired fundamental and sub-harmonics is >25 dBc typical with respect to output signal level. The low additive SSB phase noise of -136 dBc/Hz at 100 kHz offset helps the user maintain good system noise performance. The HMC444LP4 & HMC444LP4E are ideal for use in LO multiplier chains allowing reduced parts count vs. traditional approaches.

Electrical Specifications, $T_{a} = +25^{\circ} C$, Vcc= 5V

Parameter	1	Min.	Тур.	Max.	Units
Frequency Range, Input		1	.2375 - 1.4	0	GHz
Frequency Range, Output			9.9 - 11.2		GHz
Input Power Range		-15		+5	dBm
Output Power		3	6		dBm
Sub-Harmonic Suppression			25		dBc
Input Return Loss			22		dB
Output Return Loss			7		dB
SSB Phase Noise (100 kHz Offset) Pin=	0 dBm		-136		dBc/Hz
Supply Current (Icc)			68	91	mA

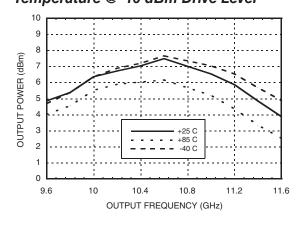
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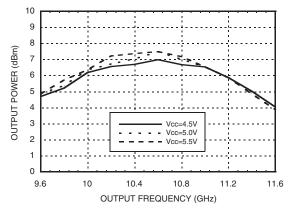


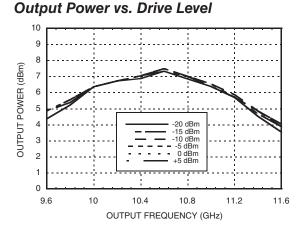
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Output Power vs. Temperature @ -10 dBm Drive Level

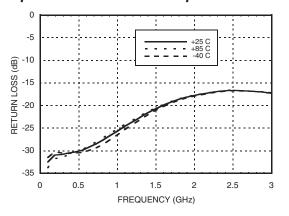


Output Power vs. Supply Voltage @ -10 dBm Drive Level

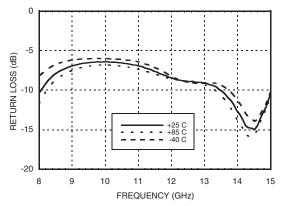




Input Return Loss vs. Temperature



Output Return Loss vs. Temperature



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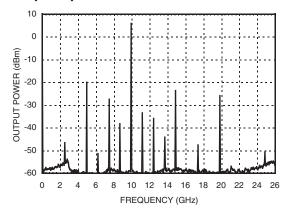




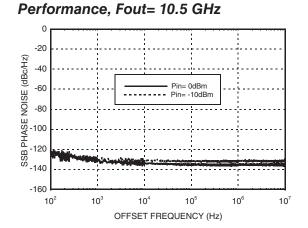
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SSB Phase Noise

Output Spectrum



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Absolute Maximum Ratings

RF Input (Vcc = +5V)	+20 dBm
Vcc	+5.5V
Channel Temperature	135 °C
Continuous Pdiss (T=85 °C) (derate 10 mW/°C above 85 °C)	650 mW
Thermal Resistance (R _{th}) (junction to ground paddle)	100 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

Typical Supply Current vs. Vcc

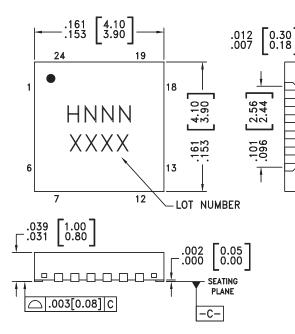
Vcc (V)	Icc (mA)
4.5	66
5.0	68
5.5	70

Note: Multiplier will operate over full voltage range shown above.



ELECTROSTATIC SENSITIVE DEVICE **OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



BOTTOM VIEW

PIN 24 -.016 [0.40] REF .008 [0.20] MIN $\Box \sqcup \Box$ PIN 1 0.56 .022 2.95 2.65 .116 04 RF/DC GROUND SQUARE

EXPOSED GROUND PADDLE MUST BE CONNECTED TO

NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

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Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC444LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H444 XXXX
HMC444LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H444 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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Pin Description

Pin Number	Function	Description	Interface Schematic
1, 2, 5 - 14, 17, 18, 20 - 24	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	RFIN	RF input needs to be DC blocked only if there is an external DC voltage applied to RF IN.	RFIN ○
4, 15	GND	All ground leads and ground paddle must be soldered to PCB RF/DC ground.	
16	RFOUT	Multiplied Output. AC coupled. No external DC blocks necessary.	
19	Vcc	Supply voltage 5V \pm 0.5V.	

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